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www.vishay.com

VS-SD1100C..C Series

Vishay Semiconductors

Standard Recovery Diodes (Hockey PUK Version), 1400 A



B-43

FEATURES

- Wide current range
- High voltage ratings up to 3200 V
- High surge current capabilities
- Diffused junction
- Hockey PUK version
- Case style B-43
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT

TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

PRODUCT SUMMARY

| | |
|-----------------------|--------------|
| $I_{F(AV)}$ | 1400 A |
| Package | B-43 |
| Circuit configuration | Single diode |

MAJOR RATINGS AND CHARACTERISTICS

| PARAMETER | TEST CONDITIONS | SD1100C..C | | UNITS |
|--------------|-----------------|-------------|--------------|-------------------|
| | | 04 to 20 | 25 to 32 | |
| $I_{F(AV)}$ | | 1400 | 1100 | A |
| | T_{hs} | 55 | 55 | °C |
| $I_{F(RMS)}$ | | 2500 | 2000 | A |
| | T_{hs} | 25 | 25 | °C |
| I_{FSM} | 50 Hz | 13 000 | 10 500 | A |
| | 60 Hz | 13 600 | 11 000 | |
| I^2t | 50 Hz | 846 | 551 | kA ² s |
| | 60 Hz | 772 | 503 | |
| V_{RRM} | Range | 400 to 2000 | 2500 to 3200 | V |
| T_J | | - 40 to 180 | - 40 to 150 | °C |

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

| TYPE NUMBER | VOLTAGE CODE | V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V | V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA |
|---------------|--------------|----------------------------------------------------------|--------------------------------------------------------------|------------------------------------------------|
| VS-SD1100C..C | 04 | 400 | 500 | 35 |
| | 08 | 800 | 900 | |
| | 12 | 1200 | 1300 | |
| | 16 | 1600 | 1700 | |
| | 20 | 2000 | 2100 | |
| | 25 | 2500 | 2600 | |
| | 30 | 3000 | 3100 | |
| | 32 | 3200 | 3300 | |



| FORWARD CONDUCTION | | | | | | |
|---------------------------------------------------------|---------------|-----------------------------------------------------------------------------------------|----------------------------|------------|------------|--------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | SD1100C..C | | UNITS |
| | | | | 04 to 20 | 25 to 32 | |
| Maximum average forward current at heatsink temperature | $I_{F(AV)}$ | 180° conduction, half sine wave Double side (single side) cooled | | 1400 (795) | 1100 (550) | A |
| | | | | 55 (85) | 55 (85) | °C |
| Maximum RMS forward current | $I_{F(RMS)}$ | 25 °C heatsink temperature double side cooled | | 2500 | 2000 | A |
| Maximum peak, one-cycle forward, non-repetitive current | I_{FSM} | t = 10 ms | No voltage reappplied | 13 000 | 10 500 | |
| | | t = 8.3 ms | No voltage reappplied | 13 600 | 11 000 | |
| | | t = 10 ms | 100 % V_{RRM} reappplied | 10 930 | 8830 | |
| | | t = 8.3 ms | 100 % V_{RRM} reappplied | 11 450 | 9250 | |
| Maximum I^2t for fusing | I^2t | t = 10 ms | No voltage reappplied | 846 | 551 | kA ² s |
| | | t = 8.3 ms | No voltage reappplied | 772 | 503 | |
| | | t = 10 ms | 100 % V_{RRM} reappplied | 598 | 390 | |
| | | t = 8.3 ms | 100 % V_{RRM} reappplied | 546 | 356 | |
| Maximum $I^2\sqrt{t}$ for fusing | $I^2\sqrt{t}$ | t = 0.1 to 10 ms, no voltage reappplied | | 8460 | 5510 | kA ² √s |
| Low level value of threshold voltage | $V_{F(TO)1}$ | $(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J$ maximum | | 0.78 | 0.84 | V |
| High level value of threshold voltage | $V_{F(TO)2}$ | $(I > \pi \times I_{F(AV)})$, $T_J = T_J$ maximum | | 0.94 | 0.88 | |
| Low level value of forward slope resistance | r_{f1} | $(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, $T_J = T_J$ maximum | | 0.35 | 0.40 | mΩ |
| High level value of forward slope resistance | r_{f2} | $(I > \pi \times I_{F(AV)})$, $T_J = T_J$ maximum | | 0.26 | 0.38 | |
| Maximum forward voltage drop | V_{FM} | $I_{pk} = 1500$ A, $T_J = T_J$ maximum $t_p = 10$ ms sinusoidal wave | | 1.31 | 1.44 | V |

| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | | |
|--------------------------------------------------|--------------|-----------------------------------------------|--|-------------|-------------|--------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | SD1100C..C | | UNITS |
| | | | | 04 to 20 | 25 to 32 | |
| Maximum junction operating temperature range | T_J | | | - 40 to 180 | - 40 to 150 | °C |
| Maximum storage temperature range | T_{Stg} | | | - 55 to 200 | | |
| Maximum thermal resistance, junction to heatsink | R_{thJ-hs} | DC operation single side cooled | | 0.076 | | K/W |
| | | DC operation double side cooled | | 0.038 | | |
| Mounting force, ± 10 % | | | | 9800 (1000) | | N (kg) |
| Approximate weight | | | | 83 | | g |
| Case style | | See dimensions - link at the end of datasheet | | B-43 | | |

| ΔR_{thJ-hs} CONDUCTION | | | | | | |
|--------------------------------|-----------------------|-------------|------------------------|-------------|---------------------|-------|
| CONDUCTION ANGLE | SINUSOIDAL CONDUCTION | | RECTANGULAR CONDUCTION | | TEST CONDITIONS | UNITS |
| | SINGLE SIDE | DOUBLE SIDE | SINGLE SIDE | DOUBLE SIDE | | |
| 180° | 0.007 | 0.007 | 0.005 | 0.005 | $T_J = T_J$ maximum | K/W |
| 120° | 0.008 | 0.008 | 0.008 | 0.008 | | |
| 90° | 0.010 | 0.010 | 0.011 | 0.011 | | |
| 60° | 0.015 | 0.015 | 0.016 | 0.016 | | |
| 30° | 0.026 | 0.026 | 0.026 | 0.026 | | |

Note

- The table above shows the increment of thermal resistance R_{thJ-hs} when devices operate at different conduction angles than DC



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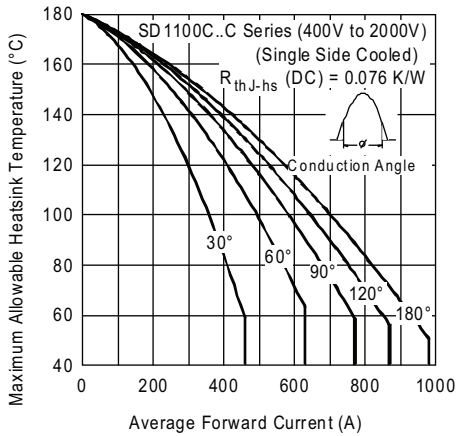


Fig. 1 - Current Ratings Characteristics

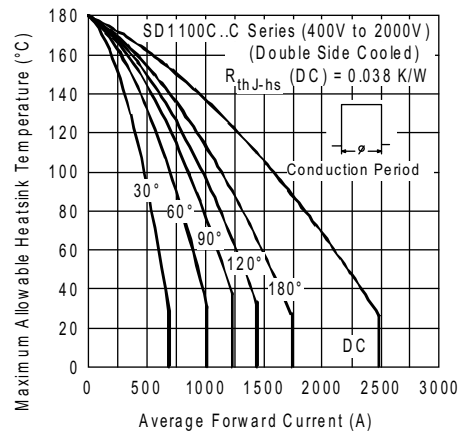


Fig. 4 - Current Ratings Characteristics

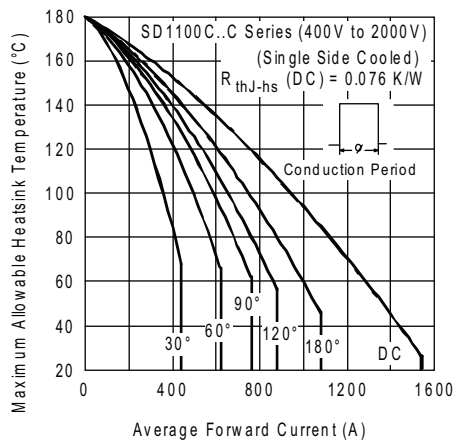


Fig. 2 - Current Ratings Characteristics

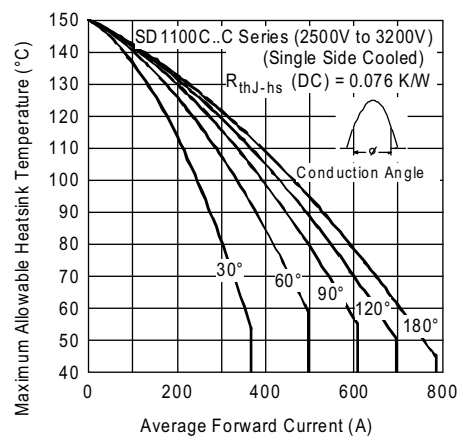


Fig. 5 - Current Ratings Characteristics

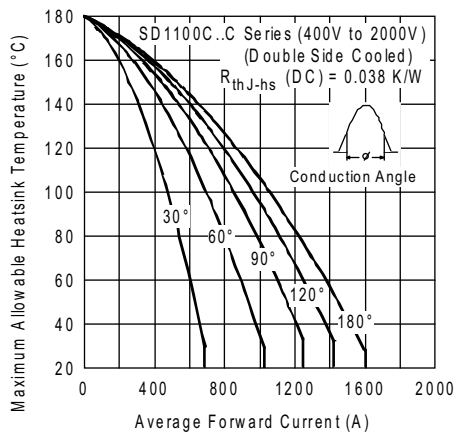


Fig. 3 - Current Ratings Characteristics

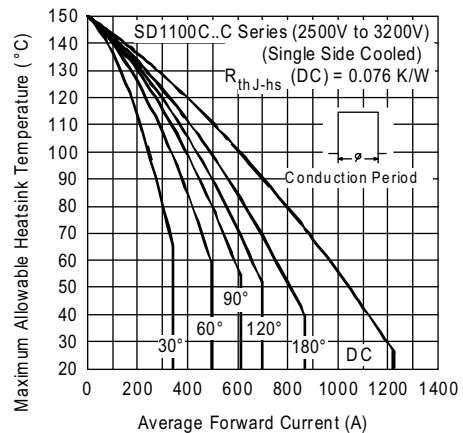


Fig. 6 - Current Ratings Characteristics



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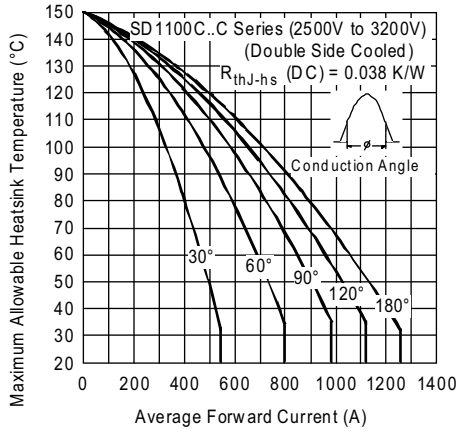


Fig. 7 - Current Ratings Characteristics

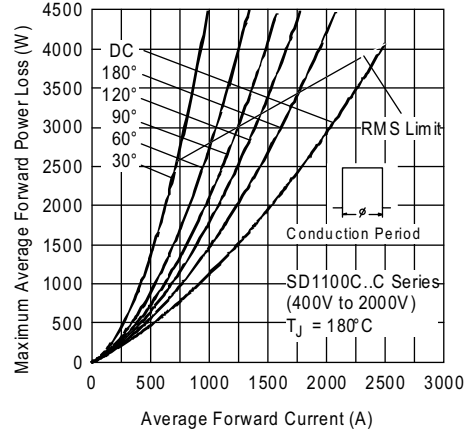


Fig. 10 - Forward Power Loss Characteristics

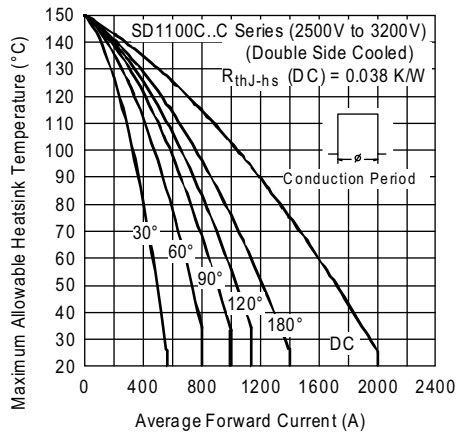


Fig. 8 - Current Ratings Characteristics

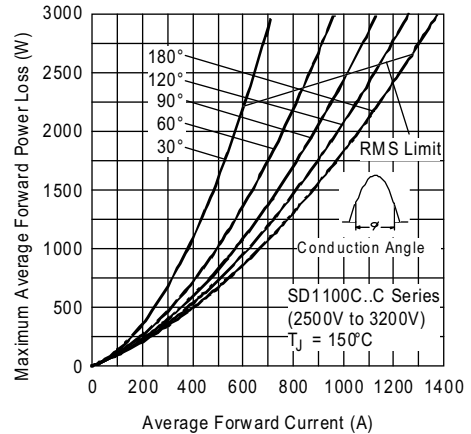


Fig. 11 - Forward Power Loss Characteristics

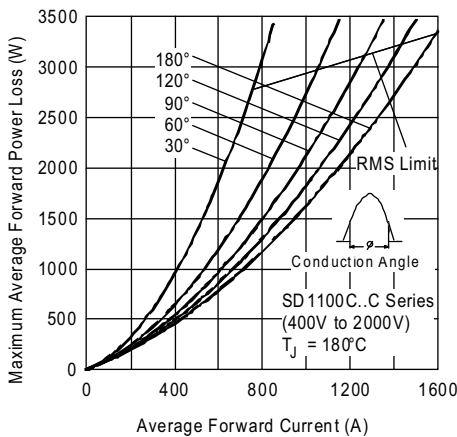


Fig. 9 - Forward Power Loss Characteristics

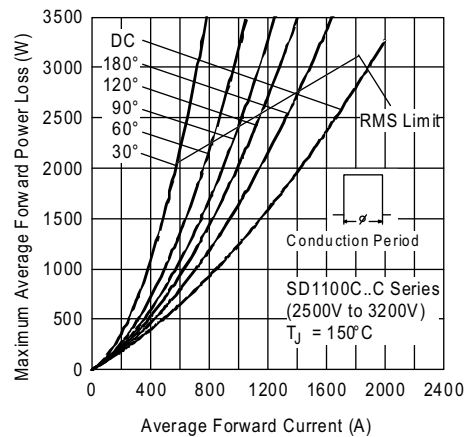


Fig. 12 - Forward Power Loss Characteristics



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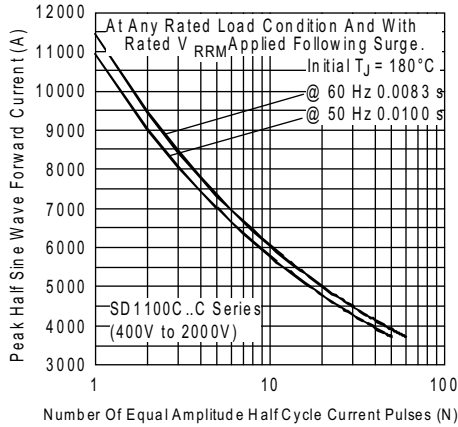


Fig. 13 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

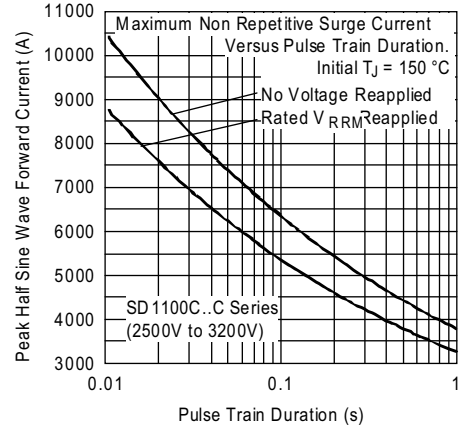


Fig. 16 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

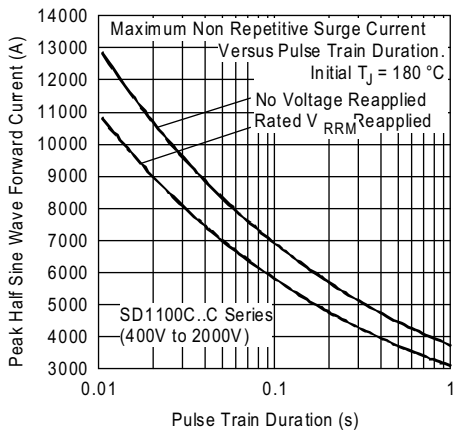


Fig. 14 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

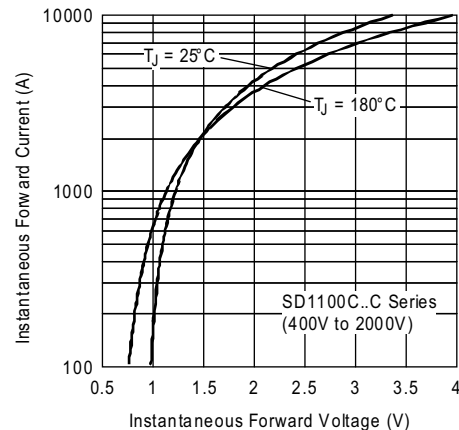


Fig. 17 - Forward Voltage Drop Characteristics

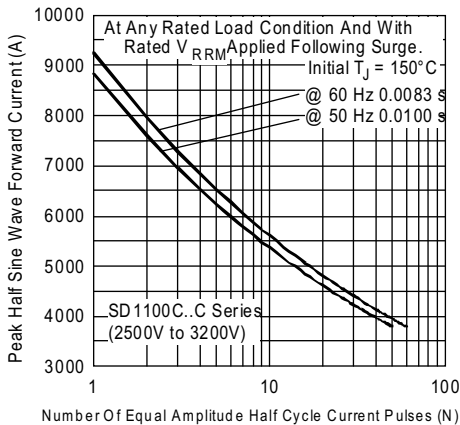


Fig. 15 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

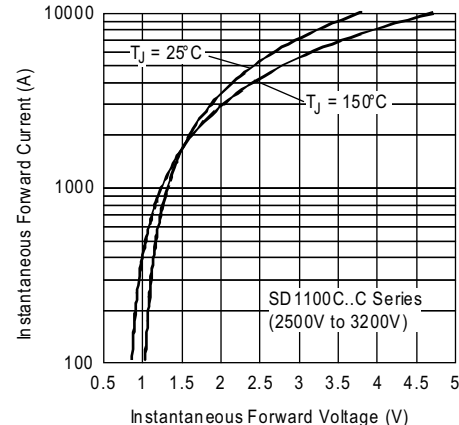


Fig. 18 - Forward Voltage Drop Characteristics



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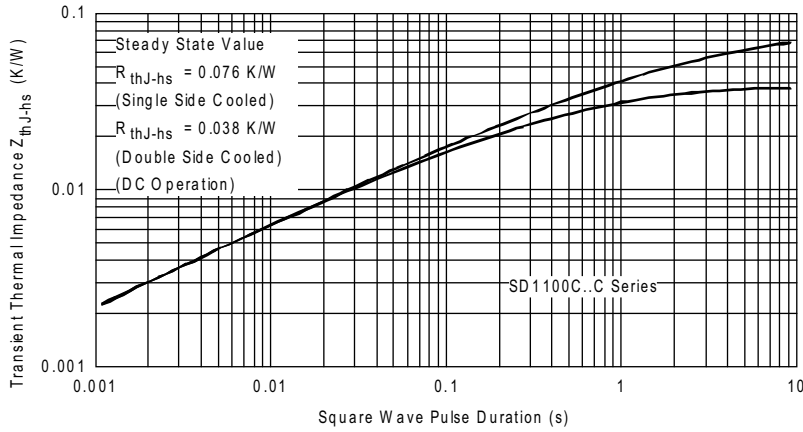


Fig. 19 - Thermal Impedance Z_{thJ-hs} Characteristics

ORDERING INFORMATION TABLE

| | | | | | | | |
|-------------|------------|-----------|------------------------------------------------------------|----------|----------|-----------|----------|
| Device code | VS- | SD | 110 | 0 | C | 32 | C |
| | ① | ② | ③ | ④ | ⑤ | ⑥ | ⑦ |
| | 1 | - | Vishay Semiconductors product | | | | |
| | 2 | - | Diode | | | | |
| | 3 | - | Essential part number | | | | |
| | 4 | - | 0 = Standard recovery | | | | |
| | 5 | - | C = Ceramic PUK | | | | |
| | 6 | - | Voltage code x 100 = V_{RRM} (see Voltage Ratings table) | | | | |
| | 7 | - | C = PUK case B-43 | | | | |

| LINKS TO RELATED DOCUMENTS | |
|----------------------------|------------------------------------------------------------------------|
| Dimensions | www.vishay.com/doc?95249 |

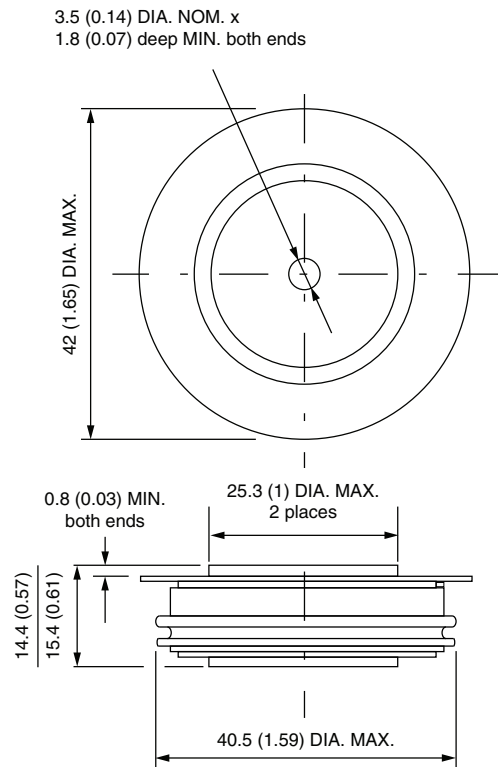


Outline Dimensions

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B-43

DIMENSIONS in millimeters (inches)



Quote between upper and lower pole pieces has to be considered after application of mounting force (see Thermal and Mechanical Specifications)



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